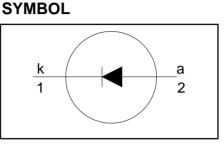
### **Rectifier diodes** fast, soft-recovery

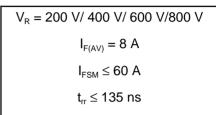
## BY229F, BY229X series

### **FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
  Isolated mounting tab



### QUICK REFERENCE DATA



### **GENERAL DESCRIPTION**

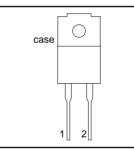
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY229F series is supplied in the conventional leaded SOD100 package. The BY229X series is supplied in the conventional leaded SOD113 package.

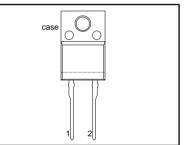
### PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	
tab	isolated	

### **SOD100**







### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MA	<b>۸X</b> .		UNIT
V <sub>RSM</sub>	Peak non-repetitive reverse	BY229F- / BY229X-	-	<b>200</b> 200	<b>400</b> 400	<b>600</b> 600	<b>800</b> 800	V
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	voltage Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage		- -	200 150 150	400 300 300	600 500 500	800 600 600	V V V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ; T <sub>hs</sub> $\leq 83$ °C sinusoidal; a = 1.57;	-			3 7	•	A A
I <sub>F(RMS)</sub> I <sub>FRM</sub>	RMS forward current Peak repetitive forward current	$\begin{split} T_{hs} &\leq 90 \ ^{\circ}\text{C} \\ t &= 25 \ \mu\text{s}; \ \delta = 0.5; \\ T_{hs} &\leq 83 \ ^{\circ}\text{C} \end{split}$	-			1 6		A A
I <sub>FSM</sub>	Peak non-repetitive forward current	t = 10  ms t = 8.3  ms sinusoidal; $T_j = 150 \text{ °C}$ prior to surge; with reapplied V <sub>RWM(max)</sub>	-		-	6 6		A A
$\begin{matrix} I^2 t \\ T_{stg} \\ T_j \end{matrix}$	I <sup>2</sup> t for fusing Storage temperature Operating junction temperature	t = 10  ms	- -40 -		1:	8 50 50		A²s °C °C

1. Neglecting switching and reverse current losses.

# Rectifier diodes fast, soft-recovery

## BY229F, BY229X series

### **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	Peak isolation voltage from both terminals to external heatsink	SOD100 package; R.H. $\leq$ 65%; clean and dustfree	-	-	1500	V
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	SOD113 package; f = 50-60 Hz; sinusoidal waveform; R.H. $\leq$ 65%; clean and dustfree	-	-	2500	V
C <sub>isol</sub>	Capacitance from pin 1 to external heatsink	f = 1 MHz	-	10	-	pF

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	heatsink	with heatsink compound without heatsink compound in free air.	-	- - 55	4.8 7.2 -	K/W K/W K/W

### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 20 A	-	1.5	1.85	V
I <sub>R</sub>	Reverse current	V <sub>R</sub> = V <sub>RWM</sub> ; T <sub>i</sub> = 125 °C		0.1	0.4	mA

### DYNAMIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t <sub>rr</sub> Q <sub>s</sub> dI <sub>R</sub> ∕dt	Reverse recovery charge	$ \begin{array}{l} I_{F}=1 \text{ A}; \ V_{R} \geq 30 \text{ V}; \ \text{-}dI_{F}/dt = 50 \text{ A}/\mu s \\ I_{F}=2 \text{ A}; \ V_{R} \geq 30 \text{ V}; \ \text{-}dI_{F}/dt = 20 \text{ A}/\mu s \\ I_{F}=2 \text{ A}; \ \text{-}dI_{F}/dt = 20 \text{ A}/\mu s \end{array} $		100 0.5 50	135 0.7 60	ns μC A/μs

BY229F, BY229X series

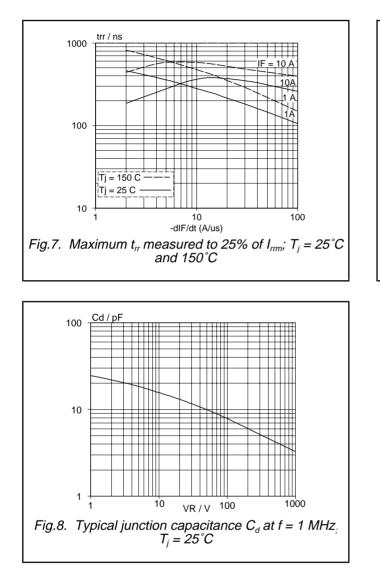
# Rectifier diodes fast, soft-recovery

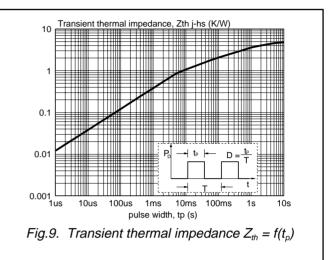
#### dl F IFS(RMS) / A 80 $I_{F}$ dt 70 IFSM 60 trr 50 time 40 30 Qs 100% 20 25% 10 I R l rrm 0 0.1s tp/s 10ms 10s 1ms 1s Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$ ; sinusoidal current waveform; $T_j = 150^{\circ}C$ prior to surge with reapplied $V_{RWM}$ . Fig.1. Definition of t<sub>rr</sub>, Q<sub>s</sub> and I<sub>rrm</sub> Ths(max) / C PF/W IF / A 30 20 54 D = 1.0 $V_0 = 1.25$ Ti = 150 C0.03 O = 25 C Tj 15 78 'n 20 0 102 10 0.1 10 <u>t</u>p tρ D = 126 5 ma 150 0 0 1.5 6 IF(AV) / A ò 0.5 Ó 8 10 12 1 4 2 . VF/V Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$ ; square wave current waveform; parameter D = dutycycle = $t_p/T$ . Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$ ; parameter $T_i$ PF/W Ths(max) / C Qs / uC 10 15 78 Tj = 150 C Vo = 1.25 V Tj = 25 C a = 1.57 Rs = 0.03 Ohm 2.2 10 10 102 2.8 1 5 126 0 150 0.1 10 0 2 4 6 8 100 IF(AV) / A -dIF/dt (A/us) Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform; parameter a = formfactor = $I_{F(RMS)}/I_{F(AV)}$ . Fig.6. Maximum $Q_s$ at $T_i = 25^{\circ}C$ and $150^{\circ}C$

Product specification

# Rectifier diodes fast, soft-recovery

# BY229F, BY229X series

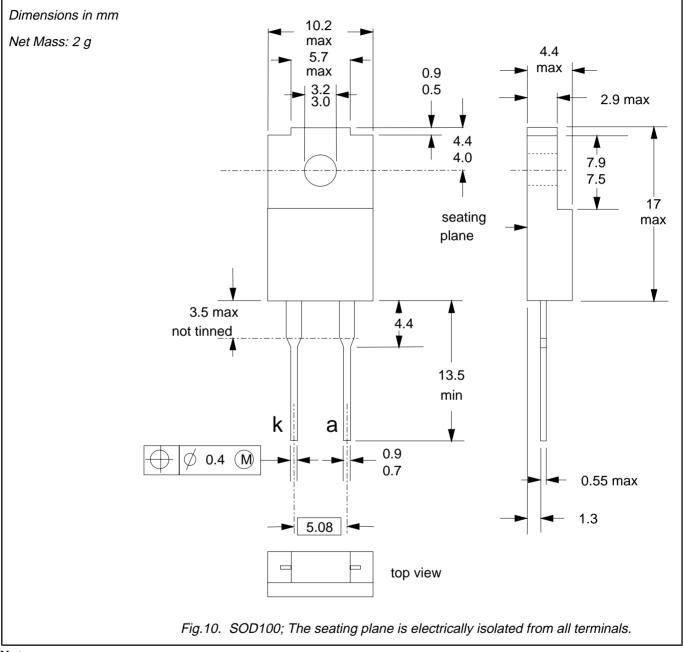




### **Rectifier diodes** fast, soft-recovery

## BY229F, BY229X series

### **MECHANICAL DATA**



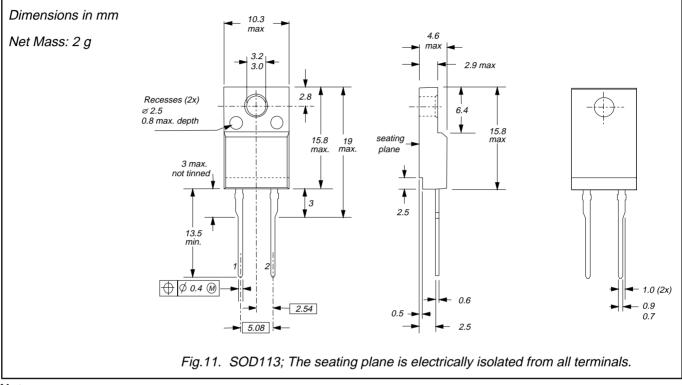


Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

### **Rectifier diodes** fast, soft-recovery

# BY229F, BY229X series

### **MECHANICAL DATA**



### Notes

Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

# Rectifier diodes fast, soft-recovery

## BY229F, BY229X series

### DEFINITIONS

Data sheet status					
Objective specification	Dbjective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	cation This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one ues may cause permanent damage to the device. These are stress ratings only and these or at any other conditions above those given in the Characteristics sections of plied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application information is given, it is advisory and does not form part of the specification.					
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